SN65LBC182
SN75LBC182

SLLS500A - MAY 2001 - REVISED MARCH 2005

## DIFFERENTIAL BUS TRANSCEIVER

## FEATURES

- One-Fourth Unit Load Allows up to 128 Devices on a Bus
- ESD Protection for Bus Terminals: - $\pm 15-k V$ Human Body Model
- $\pm 8$-kV IEC61000-4-2, Contact Discharge
- $\pm 15$-kV IEC61000-4-2, Air-Gap Discharge
- Meets or Exceeds the Requirements of ANSI Standard TIA/EIA-485-A and ISO 8482: 1987(E)
- Controlled Driver Output-Voltage Slew Rates Allow Longer Cable Stub Lengths
- Designed for Signaling Ratest Up to 250-kbps
- Low Disabled Supply Current . . . $250 \mu \mathrm{~A}$ Max
- Thermal Shutdown Protection
- Open-Circuit Fail-Safe Receiver Design
- Receiver Input Hysteresis . . . 70 mV Typ
- Glitch-Free Power-Up and Power-Down Protection


## APPLICATIONS

- Utility Meters
- Industrial Process Control
- Building Automation


## DESCRIPTION

The SN65LBC182 and SN75LBC182 are differential data line transceivers with a high level of ESD protection in the trade-standard footprint of the SN75176. They are designed for balanced transmission lines and meet ANSI standard TIA/EIA-485-A and ISO 8482. The SN65LBC182 and SN75LBC182 combine a 3 -state, differential line driver and differential input line receiver, both of which operate from a single $5-\mathrm{V}$ power supply. The driver and receiver have active-high and active-low enables, respectively, which can be externally connected together to function as a direction control.

The driver outputs and the receiver inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus. This port operates over a wide range of common-mode voltage, making the device suitable for party-line applications. The device also includes additional features for party-line data buses in electrically noisy environment applications such as industrial process control or power inverters.

The SN75LBC182 and SN65LBC182 bus pins also exhibit a high input resistance equivalent to one-fourth unit load allowing connection of up to 128 similar devices on the bus. The high ESD tolerance protects the device for cabled connections. (For an even higher level of protection, see the SN65/75LBC184, literature number SLLS236.)

The differential driver design incorporates slew-rate-controlled outputs sufficient to transmit data up to 250 kbps. Slew-rate control allows longer unterminated cable runs and longer stub lengths from the main backbone than possible with uncontrolled voltage transitions. The receiver design provides a fail-safe output of a high level when the inputs are left floating (open circuit). Very low device supply current can be achieved by disabling the driver and the receiver.
The SN65LBC182 is characterized for operation from $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$, and the SN75LBC182 is characterized for operation from $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$.
functional block diagram


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[^0]SN65LBC182D (Marked as 6LB182)
SN75LBC182D (Marked as 7LB182)
SN65LBC182P (Marked as 65LBC182)
SN75LBC182P (Marked as 75LBC182)
(TOP VIEW)


## schematic of inputs and outputs



Function Tables

| DRIVER |  |  |  |
| :---: | :---: | :---: | :---: |
| $\begin{gathered} \hline \text { INPUT } \\ \text { D } \end{gathered}$ | $\begin{gathered} \text { ENABLE } \\ \text { DE } \end{gathered}$ | OUTPUTS |  |
|  |  | A | B |
| H | H | H | L |
| L | H | L | H |
| X | L | Z | Z |
| Open | H | H | L |

RECEIVER

| DIFFERENTIAL | ENABLE |  |
| :---: | :---: | :---: |
| INPUTS | OUTPUT <br> $\mathbf{R E}$ |  |
| $\mathrm{V}_{\text {ID }} \geq 0.2 \mathrm{~V}$ | L | H |
| $-0.2 \mathrm{~V}<\mathrm{V}_{\text {ID }}<0.2 \mathrm{~V}$ | L | $?$ |
| $\mathrm{~V}_{\text {ID }} \leq-0.2 \mathrm{~V}$ | L | L |
| X | H | Z |
| Open | L | H |

AVAILABLE OPTIONS

| $\mathbf{T}_{\mathbf{A}}$ | PACKAGE |  |
| :---: | :---: | :---: |
|  | PLASTIC SMALL-OUTLINE <br> (JEDEC MS-012) | PLASTIC DUAL-IN-LINE PACKAGE <br> (JEDEC MS-001) |
| $0^{\circ} \mathrm{C}$ to $70^{\circ} \mathrm{C}$ | SN75LBC182D | SN75LBC182P |
| $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ | SN65LBC182D | SN65LBC182P |

$\dagger$ Add $R$ suffix for taped and reel.
$\dagger$ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

## absolute maximum ratings $\dagger$ over operating free-air temperature range unless otherwise noted





Electrostatic discharge: Human body model (see Note 2) A, B, GND ........................ 15 kV
All pins ............................... 3 kV
Contact discharge (IEC61000-4-2) A, B, GND ............................ 8 kV
Air discharge (IEC61000-4-2) A, B, GND ........................ 15 kV
Continuous total power dissipation ........................................... See Dissipation Rating Table
$\dagger$ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.
2. Tested in accordance with JEDEC Standard 22, Test Method A114-A.

DISSIPATION RATING TABLE

| PACKAGE | $\mathbf{T}_{\mathbf{A}} \leq \mathbf{2 5}{ }^{\circ} \mathrm{C}$ <br> POWER RATING | DERATING FACTOR $\ddagger$ <br> ABOVE TA $=25^{\circ} \mathbf{C}$ | $\mathbf{T}_{\mathbf{A}}=\mathbf{7 0} 0^{\circ} \mathbf{C}$ <br> POWER RATING | $\mathbf{T}_{\mathbf{A}}=\mathbf{8 5}{ }^{\circ} \mathbf{C}$ <br> POWER RATING |
| :---: | :---: | :---: | :---: | :---: |
| D | 725 mW | $5.8 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ | 464 mW | 377 mW |
| P | 1150 mW | $9.2 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ | 736 mW | 598 mW |

$\ddagger$ This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow. NOTE: The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature
recommended operating conditions

|  |  | MIN | NOM | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply voltage, $\mathrm{V}_{\mathrm{CC}}$ |  | 4.75 | 5 | 5.25 | V |
| Voltage at any bus I/O terminal (se | mode) $\mathrm{V}_{\text {I }}$ or $\mathrm{V}_{\text {IC }}$ | -7 |  | 12 | V |
| High-level input voltage, $\mathrm{V}_{\mathrm{IH}}$ |  | 2 |  |  |  |
| Low-level input voltage, $\mathrm{V}_{\text {IL }}$ | D, |  |  | 0.8 | V |
| Differential input voltage, $\mathrm{V}_{\text {ID }}$ (see |  | -12 |  | 12 | V |
|  | Driver | -60 |  | 60 |  |
| Output current, IO | Receiver | -8 |  | 4 | mA |
|  | SN65LBC182 | -40 |  | 85 | ${ }^{\circ} \mathrm{C}$ |
| Operaing free-air temperature, $T_{\text {A }}$ | SN75LBC182 | 0 |  | 70 | ${ }^{\circ}$ |

NOTE 3: Differential input/output bus voltage is measured at the noninverting terminal A with respect to the inverting terminal B.

## driver electrical characteristics over recommended operating conditions

| PARAMETER |  |  | TEST CON | TIONS | MIN | TYP $\dagger$ | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IK }}$ | Input clamp voltage |  | $\mathrm{l}=-18 \mathrm{~mA}$ |  | -1.5 |  |  | V |
| $\mathrm{V}_{\mathrm{O}}$ | Output voltage |  | $\mathrm{O}=0$ |  | 0 |  | $\mathrm{V}_{\mathrm{CC}}$ | V |
| \|VOD| | Differential output voltage |  | $\mathrm{R}_{\mathrm{L}}=54 \Omega$, | See Figure 1 | 1.5 | 2.2 | $\mathrm{V}_{\mathrm{CC}}$ | V |
|  |  |  | $\mathrm{V}_{\text {test }}=-7 \mathrm{~V}$ to 12 V , | See Figure 2 | 1.5 | 2.2 | $\mathrm{V}_{\mathrm{CC}}$ | V |
| $\Delta \mathrm{V}_{\text {OD }}$ | Change in magnitude of differential output voltage |  | See Figure 1 |  | -0.2 |  | 0.2 | V |
| $\mathrm{V}_{\mathrm{OC}}(\mathrm{SS})$ | Steady-state common-mode output voltage |  |  |  | 1 |  | 3 |  |
| $\triangle \mathrm{VOC}(\mathrm{SS})$ | Change in steady-state common-mode output voltage |  | See Figures 1 and 4 |  | -0.2 |  | 0.2 |  |
| VOC(PP) | Peak-to-peak change in common-mode output voltage during state transitions |  |  |  |  | 0.8 |  | V |
| Ioz | High-impedance output current |  | See receiver input currents |  |  |  |  |  |
| $\mathrm{IIH}^{\text {H }}$ | High-level input current (D, DE) |  | $\mathrm{V}_{\mathrm{I}}=2.4 \mathrm{~V}$ |  |  |  | 50 | $\mu \mathrm{A}$ |
| IIL | Low-level input current (D, DE) |  | $\mathrm{V}_{\mathrm{I}}=0.4 \mathrm{~V}$ |  | -50 |  |  | $\mu \mathrm{A}$ |
| IOS | Short-circuit output current |  | $\mathrm{V}_{\mathrm{O}}=-7 \mathrm{~V}$ to 12 V |  | -250 |  | 250 | mA |
| ICC | Supply current | SN75LBC182 | No load, DE at $\mathrm{V}_{\mathrm{CC}}, \quad \overline{\mathrm{RE}}$ at $\mathrm{V}_{\mathrm{CC}}$ |  |  | 12 | 25 | mA |
|  |  | SN65LBC182 |  |  |  | 12 | 30 |  |

$\dagger$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ and $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.

## driver switching characteristics over recommended operating conditions (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{tr}_{\mathrm{r}}$ | Differential output signal rise time | $R_{L}=54 \Omega,$ <br> See Figure 3 | $C_{L}=50 \mathrm{pF}$, | 0.25 | 0.72 | 1.2 | $\mu \mathrm{s}$ |
| $\mathrm{tf}^{\text {f }}$ | Differential output signal fall time |  |  | 0.25 | 0.73 | 1.2 |  |
| tpLH | Propagation delay time, low-to-high-level output |  |  |  |  | 1.3 |  |
| tPHL | Propagation delay time, high-to-low-level output |  |  |  |  | 1.3 |  |
| $\mathrm{t}_{\text {sk }}(\mathrm{p})$ | Pulse skew (tPHL - tPLH) |  |  |  | 0.075 | 0.15 |  |
| tPZH | Output enable time to high level | $\mathrm{R}_{\mathrm{L}}=110 \Omega$, | See Figure 5 |  |  | 3.5 | $\mu \mathrm{S}$ |
| tPHZ | Output disable time from high level |  |  |  |  | 3.5 |  |
| tPZL | Output enable time to low level | $\mathrm{R}_{\mathrm{L}}=110 \Omega$, | See Figure 6 |  |  | 3.5 | $\mu \mathrm{s}$ |
| tpLZ | Output disable time from low level |  |  |  |  | 3.5 |  |

receiver electrical characteristics over recommended operating conditions (unless otherwise noted)

| PARAMETER | TEST CONDITIONS |  | MIN | TYP† | MAX | UNIT <br> V |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {IT }+} \quad$ Positive-going input threshold voltage |  |  |  |  | 0.2 |  |
| $\mathrm{V}_{\text {IT- }}$ Negative-going input threshold voltage |  |  | -0.2 |  |  | V |
| $\mathrm{V}_{\text {hys }}$ Hysteresis voltage ( $\mathrm{V}_{\text {IT }}$ - $\mathrm{V}_{\text {IT- }}$ ) |  |  |  | 70 |  | mV |
| $\mathrm{V}_{\mathrm{IK}} \quad$ Enable-input clamp voltage | $\mathrm{I}_{1}=-18 \mathrm{~mA}$ |  | -1.5 |  |  | V |
| $\mathrm{V}_{\mathrm{OH}}$ High-level output voltage | $\mathrm{V}_{\mathrm{ID}}=200 \mathrm{mV}$, $\mathrm{I}=-8 \mathrm{~mA}$, | See Figure 7 | 2.8 |  |  | V |
| $\mathrm{V}_{\mathrm{OL}}$ Low-level output voltage | $\mathrm{V}_{\mathrm{ID}}=200 \mathrm{mV}, \mathrm{I}_{\mathrm{O}}=4 \mathrm{~mA}$, | See Figure 7 |  |  | 0.4 | V |
| IOZ High-impedance-state output current | $\mathrm{V}_{\mathrm{O}}=0.4$ to 2.4 V |  |  |  | $\pm 1$ | $\mu \mathrm{A}$ |
| II Bus input current | $\mathrm{V}_{\mathrm{IH}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}$ | Other input at 0 V |  |  | 250 | $\mu \mathrm{A}$ |
|  | $\mathrm{V}_{\mathrm{IH}}=12 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=0 \mathrm{~V}$ |  |  |  | 250 |  |
|  | $\mathrm{V}_{\mathrm{IH}}=-7 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}$ |  | -200 |  |  |  |
|  | $\mathrm{V}_{\mathrm{IH}}=-7 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=0 \mathrm{~V}$ |  | -200 |  |  |  |
| $\mathrm{I}_{\mathrm{IH}} \quad$ High-level input current ( $\left.\overline{\mathrm{RE}}\right)$ | $\mathrm{V}_{\mathrm{IH}}=2 \mathrm{~V}$ |  |  |  | 50 | $\mu \mathrm{A}$ |
| IIL Low-level input current ( $\overline{\mathrm{RE}})$ | $\mathrm{V}_{\mathrm{IL}}=0.8 \mathrm{~V}$ |  | -50 |  |  | $\mu \mathrm{A}$ |
| Supply current | No load | DE at $0 \mathrm{~V}, \overline{\mathrm{RE}}$ at 0 V |  |  | 3.5 | mA |
|  |  | $\overline{\mathrm{DE}}$ at $0 \mathrm{~V}, \overline{\mathrm{RE}}$ at $\mathrm{V}_{\mathrm{CC}}$ |  | 175 | 250 | $\mu \mathrm{A}$ |

$\dagger$ All typical values are at $\mathrm{V}_{\mathrm{CC}}=5 \mathrm{~V}$ and $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$.
receiver switching characteristics over recommended operating conditions (unless otherwise noted)

| PARAMETER |  | TEST CONDITIONS |  | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{tr}_{\mathrm{r}}$ | Differential output signal rise time | $C_{L}=50 \mathrm{pF}$, | See Figure 7 |  | 20 |  | ns |
| $\mathrm{t}_{\mathrm{f}}$ | Differential output signal fall time |  |  |  | 20 |  |  |
| tPLH | Propagation delay time, low-to-high-level output |  |  |  |  | 150 |  |
| tpHL | Propagation delay time, high-to-low-level output |  |  |  |  | 150 |  |
| tPZH | Output enable time to high level | See Figure 8 |  |  |  | 100 | ns |
| tPZL | Output enable time to low level |  |  |  |  | 100 |  |
| tphz | Output disable time from high level |  |  |  |  | 100 | ns |
| tPLZ | Output disable time from low level |  |  |  |  | 100 |  |
| $\mathrm{t}_{\text {sk }}(\mathrm{p})$ | Pulse skew \|t ${ }_{\text {PHL }}$ - tPLH ${ }^{\text {l }}$ |  |  |  |  | 50 | ns |

PARAMETER MEASUREMENT INFORMATION

†Includes probe and jig capacitance
Figure 1. Driver Test Circuit, $\mathrm{V}_{\mathrm{OD}}$ and $\mathrm{V}_{\mathrm{OC}}$ Without Common-Mode Loading


Figure 2. Driver Test Circuit, $\mathrm{V}_{\mathrm{OD}}$ With Common-Mode Loading


Figure 3. Driver Switching Test Circuit and Waveforms


Figure 4. $V_{\mathrm{OC}}$ Definitions

## PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT


VOLTAGE WAVEFORMS

NOTES: A. The input pulse is supplied by a generator having the following characteristics: $\mathrm{PRR}=1.25 \mathrm{kHz}, 50 \%$ duty $\mathrm{cycle}, \mathrm{t}_{\mathrm{r}} \leq 10 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{f}} \leq 10 \mathrm{~ns}, \mathrm{Z}_{\mathrm{O}}=50 \Omega$.
B. $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.

Figure 5. Driver $\mathrm{t}_{\text {PZH }}$ and $\mathrm{t}_{\text {PHZ }}$ Test Circuit and Voltage Waveforms


NOTES: A. The input pulse is supplied by a generator having the following characteristics: $\mathrm{PRR}=1.25 \mathrm{kHz}, 50 \% \mathrm{duty} \mathrm{cycle}, \mathrm{t}_{\mathrm{r}} \leq 10 \mathrm{~ns}$, $\mathrm{t}_{\mathrm{f}} \leq 10 \mathrm{~ns}, \mathrm{Z}_{\mathrm{O}}=50 \Omega$.
B. $\mathrm{C}_{\mathrm{L}}$ includes probe and jig capacitance.

Figure 6. Driver tpzL and tpLz Test Circuit and Voltage Waveforms


NOTE A: This value includes probe and jig capacitance ( $\pm 10 \%$ ).
Figure 7. Receiver $t_{\text {PLH }}$ and tpHL $^{\text {Test Circuit and Voltage Waveforms }}$

## PARAMETER MEASUREMENT INFORMATION



A


NOTE A: This value includes probe and jig capacitance ( $\pm 10 \%$ ).
Figure 8. Receiver $t_{\text {PZL }}, t_{\text {PLZ }}, t_{\text {PZH }}$, and $t_{\text {PHZ }}$ Test Circuit and Voltage Waveforms

## TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS


Figure 13

APPLICATION INFORMATION


NOTE A: The line should be terminated at both ends in its characteristic impedance ( $R_{T}=Z_{O}$ ). Stub lengths off the main line should be kept as short as possible.

Figure 14. Typical Application Circuit
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## PACKAGING INFORMATION

| Orderable Device | Status ${ }^{(1)}$ | Package Type | Package Drawing | Pins | Package Qty | $\text { Eco Plan }{ }^{(2)}$ | Lead/Ball Finish | MSL Peak Temp ${ }^{(3)}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SN65LBC182D | ACTIVE | SOIC | D | 8 | 75 | $\begin{gathered} \text { Green (RoHS \& } \\ \text { no } \mathrm{Sb} / \mathrm{Br} \text { ) } \end{gathered}$ | CU NIPDAU | Level-1-260C-UNLIM |
| SN65LBC182DG4 | ACTIVE | SOIC | D | 8 | 75 | $\begin{gathered} \text { Green (RoHS \& } \\ \text { no } \mathrm{Sb} / \mathrm{Br} \text { ) } \end{gathered}$ | CU NIPDAU | Level-1-260C-UNLIM |
| SN65LBC182DR | ACTIVE | SOIC | D | 8 | 2500 | $\begin{gathered} \text { Green (RoHS \& } \\ \text { no Sb/Br) } \end{gathered}$ | CU NIPDAU | Level-1-260C-UNLIM |
| SN65LBC182DRG4 | ACTIVE | SOIC | D | 8 | 2500 | $\begin{gathered} \text { Green (RoHS \& } \\ \text { no Sb/Br) } \end{gathered}$ | CU NIPDAU | Level-1-260C-UNLIM |
| SN65LBC182P | ACTIVE | PDIP | P | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N/A for Pkg Type |
| SN65LBC182PE4 | ACTIVE | PDIP | P | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N/ A for Pkg Type |
| SN75LBC182D | ACTIVE | SOIC | D | 8 | 75 | $\begin{gathered} \text { Green (RoHS \& } \\ \text { no } \mathrm{Sb} / \mathrm{Br} \text { ) } \end{gathered}$ | CU NIPDAU | Level-1-260C-UNLIM |
| SN75LBC182DG4 | ACTIVE | SOIC | D | 8 | 75 | $\begin{gathered} \text { Green (RoHS \& } \\ \text { no } \mathrm{Sb} / \mathrm{Br} \text { ) } \end{gathered}$ | CU NIPDAU | Level-1-260C-UNLIM |
| SN75LBC182DR | ACTIVE | SOIC | D | 8 | 2500 | $\begin{gathered} \hline \text { Green (RoHS \& } \\ \text { no } \mathrm{Sb} / \mathrm{Br} \text { ) } \\ \hline \end{gathered}$ | CU NIPDAU | Level-1-260C-UNLIM |
| SN75LBC182DRG4 | ACTIVE | SOIC | D | 8 | 2500 | $\begin{gathered} \text { Green (RoHS \& } \\ \text { no } \mathrm{Sb} / \mathrm{Br} \text { ) } \end{gathered}$ | CU NIPDAU | Level-1-260C-UNLIM |
| SN75LBC182P | ACTIVE | PDIP | P | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N/A for Pkg Type |
| SN75LBC182PE4 | ACTIVE | PDIP | P | 8 | 50 | Pb-Free (RoHS) | CU NIPDAU | N/ A for Pkg Type |

${ }^{(1)}$ The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.
${ }^{(2)}$ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS \& no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The $\mathrm{Pb}-\mathrm{Free} / \mathrm{Green}$ conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed $0.1 \%$ by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb -Free products are suitable for use in specified lead-free processes.
Pb -Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb -Free (RoHS compatible) as defined above.
Green (RoHS \& no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants ( Br or Sb do not exceed $0.1 \%$ by weight in homogeneous material)
${ }^{(3)}$ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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## PACKAGE OPTION ADDENDUM

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## TAPE AND REEL INFORMATION


*All dimensions are nominal

| Device | Package <br> Type | Package <br> Drawing | Pins | SPQ | Reel <br> Diameter <br> $(\mathbf{m m})$ | Reel <br> Width <br> W1 $(\mathbf{m m})$ | A0 $(\mathbf{m m})$ | B0 $(\mathbf{m m})$ | K0 (mm) | P1 <br> $(\mathbf{m m})$ | W <br> $(\mathbf{m m})$ | Pin1 <br> Quadrant |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SN65LBC182DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| SN65LBC182DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| SN75LBC182DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| SN75LBC182DR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| SN65LBC182DR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| SN65LBC182DR | SOIC | D | 8 | 2500 | 346.0 | 346.0 | 29.0 |
| SN75LBC182DR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| SN75LBC182DR | SOIC | D | 8 | 2500 | 346.0 | 346.0 | 29.0 |

D (R-PDSO-G8)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $.006(0,15)$ per end.
D Body width does not include interlead flash. Interlead flash shall not exceed $.017(0,43)$ per side.
E. Reference JEDEC MS-012 variation AA.


NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-001

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[^0]:    †The signaling rate of a line, is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

